# MSKSEMI 美森科













ESD

15

TSS

MOV

GDT

PIFD

LMV393DR2G(MS)

**Product specification** 





### **GENERAL DESCRIPTION**

The LMV393DR2G (MS) dual comparator version is an open drain output comparator for maximum flexibility. It can operate in the voltage range of 2.1V to 5.5V, and each channel has 50 at low output μ Low power consumption of A (TYPE).

The LMV393DR2G (MS) are themost cost-effective solutions for applications where low voltage operation, low power and space saving are the primary specifications in circuit design for portable consumer products.

The LMV393DR2G (MS) areavailable in Green SOP-8 packages. It operates over an ambient temperature range of -40°C to +85°C.

#### **FEATURES**

- Supply Range: +2.1V to +5.5V
- Low Supply Current
- 50µA (TYP) per channel at VS = 5V and output low
- Input Common-Mode Voltage Range Includes Ground
- Low Output Saturation Voltage 100mV Typical
- Open-Drain Output for Maximum Flexibility
- SPECIFIED UP TO +125°C
- Micro SIZE PACKAGES: SOP-8

## **APPLICATIONS**

- Hysteresis Comparators
- Oscillators
- Window Comparators
- Industrial Equipment
- Test and Measurement

### **Reference News**

PACKAGE OUTLINE	Marking
	MSKSEMI LMV393DR2G MS ***
SOP-8	LMV393DR2G(MS)

#### SIMPLIFIED SCHEMATIC

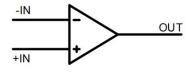


Figure 1. Simplified Schematic



## **Absolute Maximum Ratings(1)**

		MIN	MAX	UNIT
	Supply, V <sub>s</sub> =(V+) - (V-)		7	V
Voltage	Input pin (IN+, IN-) (2)	(V-) - 0.3	(V+) + 0.3	V
	Signal output pin (3)	(V-) - 0.3	(V+) + 0.3	V
Current	Signal Input pin (IN+, IN-) (2)	-10	10	mA
Current	Signal output pin (3)	-55	55	mA
	Operating Range	-55	125	°C
Temperature	Storage	-65	150	°C
	Junction		150	°C

<sup>(1)</sup> Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

## **ESD Ratings**

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	±2000	V
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	±1000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

## **Recommended Operating Conditions**

		MIN	MAX	UNIT
Supply voltage, Vs= (V+) - (V-)	Single-supply	2.1	5.5	V
Supply voltage, vs= (v·)-(v-)	Dual-supply	±0.9	±2.75	V

<sup>(2)</sup> Output terminals are diode-clamped to the power-supply rails. Output signals that can swing more than 0.5V beyond the supply rails should be current-limited to ±55mA or less.

<sup>(3)</sup> Short-circuit from output to VCC can cause excessive heating and eventual destruction.

<sup>(2)</sup> JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

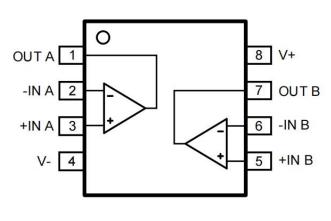


## PACKAGE/ORDER INFORMATION

MODEL	OPERATING TEMPERATURE RANGE	PACKAE DESCRIPTION	QTY
LMV393DR2G(MS)	-40°C~85°C	SOP-8	2500

# Pin Configuration and Functions (Top View)

LMV393DR2G(MS)



SOP-8

# **Pin Description**

Pin	Pin Number	I/O	Description
Name	SOP-8		Beschpiten
OUTA	1	0	Output, channel A
-INA	2	I	Inverting input, channel A
+INA	3	I	Noninverting input, channel A
V-	4	-	Negative(lowest) power supply
+INB	5	I	Noninverting input, channel B
-INB	6	I	Inverting input, channel B
OUTB	7	0	Output, channel B
V+	8	-	Positive (highest) power supply



# ELECTRICAL CHARACTERISTICS(Vs = 5.0V)

At  $T_A = 25$ °C,  $V_{CM} = V_S/2$ , unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY					
Operating Voltage Range		2.1		5.5	V
Quiescent Current/per channel (Output High)			29		μA
Quiescent Current/per channel (Output Low)			50		μА
Power Supply Rejection Ratio	Vs = 2.1V to 5.5V, V <sub>CM</sub> = V <sub>S</sub> /2		70		dB
INPUT					
Input offset voltage		-4	±0.8	4	mV
Input Offset Voltage Drift			0.8		μV/°C
Common-Mode Voltage Range		(V-)-0.1		4.5	V
Common-mode Rejection Ratio	V <sub>CM</sub> = -0.1V to 4.5V		70		dB
Input Bias Current			2		pA
Input Offset Current			1		pА
OUTPUT			1	I	
Saturation Voltage	lo≤4mA		100		mV
Output Pull-up Voltage Range				5.6	V
Output Current(sinking)	V <sub>0</sub> ≤1.5V		50		mA
SWITCHING			1		
Description Deleville	$R_{PU}$ =5.1 $K\Omega$ , Overdrive =10 $mV$		460		
Propagation Delay H To L	$R_{PU}$ =5.1 $K\Omega$ , Overdrive =100 $mV$		400		
D	$R_{PU}$ =5.1 $K\Omega$ , Overdrive =10 $mV$		950		- ns
Propagation Delay L To H	$R_{PU}$ =5.1 $K\Omega$ , Overdrive =100 $mV$		850		
Fall Time	$R_{PU}$ =5.1KΩ, Overdrive =100mV		36		ns



## **ELECTRICAL CHARACTERISTICS(Vs = 2.7V)**

 $A_t T_A = 25$ °C,  $V_{CM} = V_S/2$ , unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY					
Operating Voltage Range		2.1		5.5	V
Quiescent Current/per channel (Output High)			17		μА
Quiescent Current/per channel (Output Low)			30		μА
Power Supply Rejection Ratio	Vs = 2.1V to 5.5V, V <sub>CM</sub> = V <sub>S</sub> /2		70		dB
INPUT					
Input offset voltage		-4	±0.8	4	mV
Input Offset Voltage Drift			0.8		μV/°C
Common-Mode Voltage Range		(V-)-0.1		2.2	V
Common-mode Rejection Ratio	V <sub>CM</sub> = -0.1V to 2.2V		70		dB
Input Bias Current			2		pA
Input Offset Current			1		рА
OUTPUT					
Saturation Voltage	l <sub>o</sub> ≤4mA		82		mV
Output Pull-up Voltage Range				5.6	V
Output Current(sinking)	V <sub>0</sub> ≤1.5V		20		mA
SWITCHING		1	1	1	- 1
Propagation Delay H To L	$R_{PU}=5.1K\Omega$ , Overdrive =10mV		420		
Tropagation Delay IT To E	$R_{PU}$ =5.1K $\Omega$ , Overdrive =100 mV		380		ns
Propagation Delay L To H	R <sub>PU</sub> =5.1KΩ, Overdrive =10mV		900		5
	$R_{PU}$ =5.1K $\Omega$ , Overdrive =100 mV		880		
Fall Time	R <sub>PU</sub> =5.1KΩ, Overdrive =100 mV		36		ns



## **ELECTRICAL CHARACTERISTICS(VS =2.1V)**

 $A_t T_A = 25$ °C,  $V_{CM} = V_S/2$ , unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY					
Operating Voltage Range		2.1		5.5	V
Quiescent Current/per channel (Output High)			15		μА
Quiescent Current/per channel (Output Low)			26		μА
Power Supply Rejection Ratio	$V_S = 2.1V \text{ to } 5.5V,$ $V_{CM} = V_S/2$		70		dB
INPUT					
Input offset voltage		-4	±0.8	4	mV
Input Offset Voltage Drift			0.8		μV/°C
Common-Mode Voltage Range		(V-)-0.1		1.3	V
Common-mode Rejection Ratio	$V_{CM} = -0.1V \text{ to } 1.3V$		70		dB
Input Bias Current			2		рА
Input Offset Current			1		рА
OUTPUT					
Saturation Voltage	lo≤4mA		96		mV
Output Pull-up Voltage Range				5.6	V
Output Current(sinking)	V <sub>0</sub> ≤1.5V		7		mA
SWITCHING	,				
Propagation Delay H To L	$R_{PU}$ =5.1 $K\Omega$ , Overdrive =10 $mV$		480		ns
Tropagation Bolay Trice	$R_{PU}$ =5.1 $K\Omega$ , Overdrive =100 $mV$		430		
Propagation Delay L To H	$R_{PU}$ =5.1 $K\Omega$ , Overdrive =10 $mV$		820		
	$R_{PU}$ =5.1 $K\Omega$ , Overdrive =100 $mV$		800		
Fall Time	R <sub>PU</sub> =5.1KΩ, Overdrive =100mV		38		ns



## TYPICAL CHARACTERISTICS

At  $T_A$  = 25°C,  $V_S$  = +5V,  $V_{CM}$  =  $V_S/2$ , unless otherwise noted.

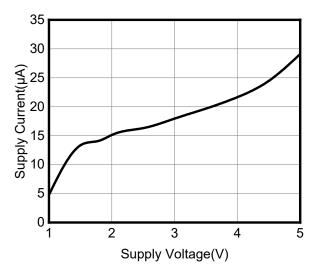


Figure 2. Supply Current vs Supply Voltage

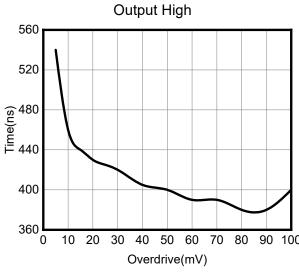


Figure 4. Response Time vs Input Overdrives Negative Transition(V<sub>CC</sub>=5V)

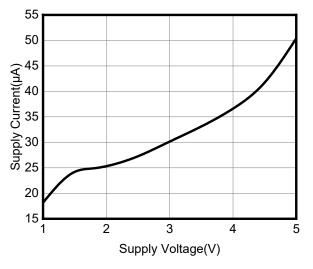


Figure 3. Supply Current vs Supply Voltage

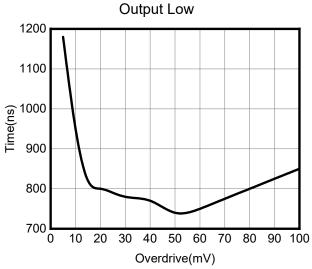
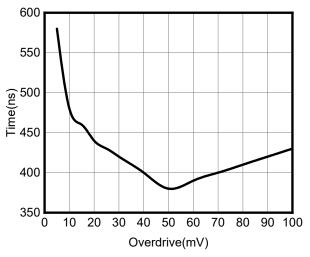


Figure 5. Response Time vs Input Overdrives Positive Transition(V<sub>CC</sub>=5V)





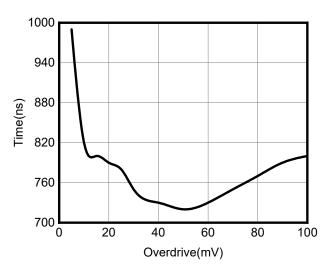


Figure 6. Response Time vs Input Overdrives Negative Transition(V<sub>CC</sub>=2.1V)

Figure 7. Response Time vs Input Overdrives Positive Transition(V<sub>CC</sub>=2.1V)

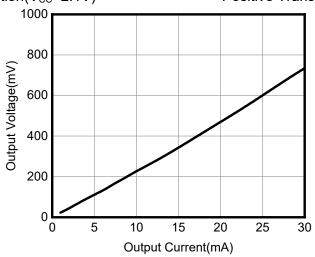


Figure 8. Output Voltage vs Output Current



## **DETAILED DESCRIPTION**

#### Overview

The LLMV393DR2G(MS) family of comparators can operate up to 5.5V on the supply pin. This standard device has proven ubiquity and versatility across a wide range of applications.

This is due to its low power and high speed. The opendrain output allows the user to configure the output's logic low voltage ( $V_{OL}$ ) and can be utilized to enable the comparator to be used in AND functionality.

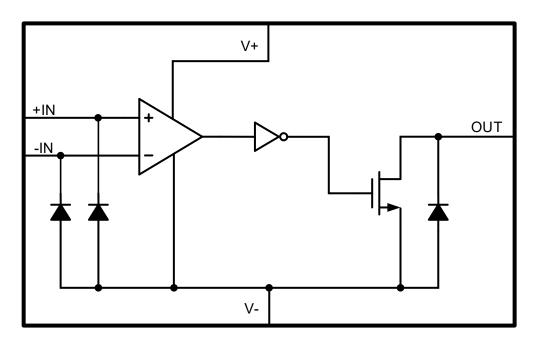


Figure 9. Functional Block Diagram



### APPLICATION and IMPLEMENTATION

#### **Application Information**

LMV393DR2G(MS) will typically be used to compare a single signal to a reference or two signals against each other. Many users take advantage of the open drain output (logic high with pull-up) to drive the comparison logic output to a logic voltage level to an MCU or logic device.

#### **Typical Application**

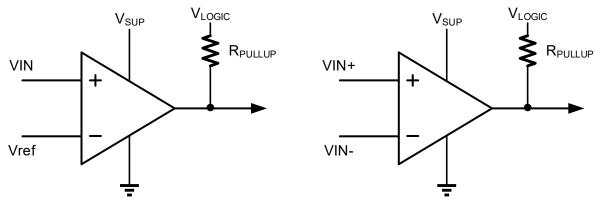


Figure 10. Typical Application Schematic

#### **Power Supply Recommendations**

For fast response and comparison applications with noisy or AC inputs, it is recommended to use a bypass capacitor on the supply pin to reject any variation on the supply voltage. This variation causes temporary fluctuations in the comparator's input common mode range and create an inaccurate comparison.

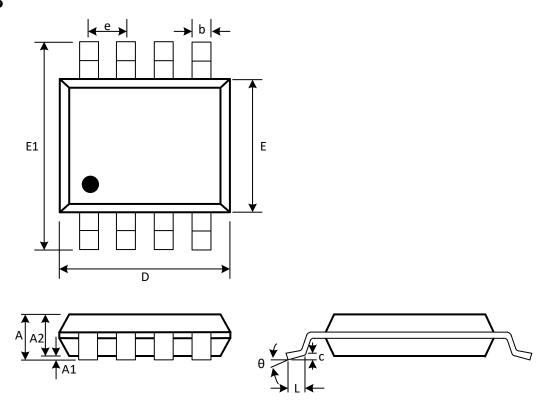
## Layout

#### **Layout Guidelines**

For accurate comparator applications without hysteresis it is important maintain a stable power supply with minimized noise and glitches, which can affect the high-level input common mode voltage range. In order to achieve this, it is best to add a bypass capacitor between the supply voltage and ground. This should be implemented on the positive power supply and negative supply (if available). If a negative supply is not being used, do not put a capacitor between the IC's GND pin and system ground.



## SOP-8



(Unit: mm)

Symbol	Min	Max	
А	1.350	1.750	
A1	0.100	0.250	
A2	1.350	1.550	
b	0.330	0.510	
С	0.170	0.250	
D	4.800	5.000	
е	1.270(BSC)		
E	3.800	4.000	
E1	5.800	6.200	
L	0.400	1.270	
θ	0°	8°	



## **Attention**

- Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.
- MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all MSKSEMI Semiconductor products described or contained herein.
- Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer'sproducts or equipment.
- MSKSEMI Semiconductor. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with someprobability. It is possiblethat these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents—or events cannot occur. Such measures include but are not limited to protective circuits anderror prevention circuitsfor safedesign, redundant design, and structural design.
- In the event that any or all MSKSEMI Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from theauthorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. Whendesigning equipment, referto the "Delivery Specification" for the MSKSEMI Semiconductor productthat you intend to use.

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Analog Comparators category:

Click to view products by MSKSEMI manufacturer:

Other Similar products are found below:

SC2903VDR2G LM2901SNG LM339SNG 55122 5962-8757203IA NTE911 LM339EDR2G NTE922 UPC177GR-9LG-E2-A
HT393VRMZ LM2903YD NCV2200SN1T1G LM2903A-SR LM339A-SR HT339ARQZ LM2901XP MS8923 LM239AM/TR
LM393LVQDGKRQ1 LM393LVQPWRQ1 LM2903BWDSGRQ1 TLV3801DSGT LM331BXF AD790JRZ-REEL LM339A-TR
LT6700HVHS6-1#TRPBF GS2903-SR LMV7219M5/TR LMV7239M5/TR LM293ADR-HXY LM293DR-HXY LM339N-HXY LM393PHXY IL339DT LM2901XQ RS331XF-Q1 MIC842NYMT-TR LM393FVM-TR LM393P TLV3602QDGKRQ1 TLV7032QDGKRQ1
TLV3601QDBVRQ1 LM2901BQPWRQ1 TLV3603DCKR TLV3603DCKT LMV331IDBVR(MS) LMV331TP-MS LMV331W5-7(MS)
MCP6561UT-E(MS) LMV331-MS